NSN 5961-01-064-2258



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-064-2258 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.260 inches and 0.325 inches Overall Diameter: Between 0.265 inches and 0.285 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 collector to base voltage/static/emitter open and 35.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 425.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13499-352-0906 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: